## Supplementary Information for Crystal Structure and Physical Properties of Indium Flux Grown $RE_2AuSi_3$ (RE = Eu, Yb)

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**Figure S1.** Comparison of PXRD pattern of polycrystalline sample of  $Eu_2AuSi_3$  with that of simulated pattern obtained from the data of X-ray diffraction on a single crystal.



**Figure S2.** Comparison of PXRD pattern of polycrystalline sample of Yb<sub>2</sub>AuSi<sub>3</sub> with that of simulated pattern obtained from the data of X-ray diffraction on a single crystal.



**Figure S3.** Temperature dependent molar magnetic susceptibility of  $Yb_2AuSi_3$  after weeks of synthesis at 1 k Oe applied magnetic field. The inset represents the plot of  $\chi T$  vs. temperature at the same field. The effective magnetic moment is 2.80  $\mu_B$ / Yb.



Figure S4. Field dependence of magnetic moment of oxidized Yb<sub>2</sub>AuSi<sub>3</sub>.